



EMR101_C

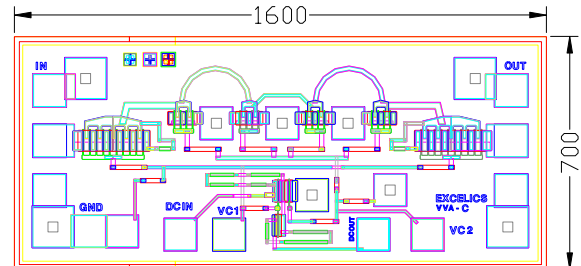
DC – 26GHz VOLTAGE VARIABLE ATTENUATOR MMIC

FEATURES

- Broadband Performance: DC-26GHz
- Wide Attenuation Range: 25dB
- Low Insertion Loss: 2.5dB
- Good Return Loss: 10dB

APPLICATIONS

- Point-to-point and point-to-multipoint radio



ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

PARAMETERS/TEST CONDITIONS		MIN	TYP	MAX	UNIT
Operating Frequency Range		DC		26	GHz
Input Power at 1dB Compression		6	8		dBm
Input Power at 0.25dB Compression		-5	-2		dBm
Minimum Attenuation	(DC - 8GHz)		1.5	2.5	dB
	(8 - 26GHz)		2.5	3.5	dB
Maximum Attenuation	(DC – 8GHz)		25	30	dB
	(8 - 26GHz)		30	35	dB
Return Loss	@min. attenuation	10	15		dB
	@max. attenuation	10	12		dB

ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION^{1,2}

RF Input Power	+16dBm
Control Voltage	+1.0 to -8 Volts
Storage Temperature	-65 to 150 deg C
Operating Temperature	-55 to +125 deg C

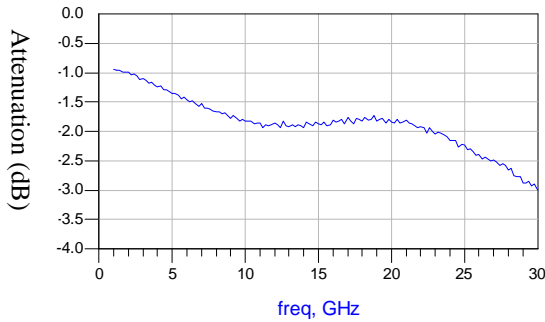
1. Operating the device beyond any of the above rating may result in permanent damage.



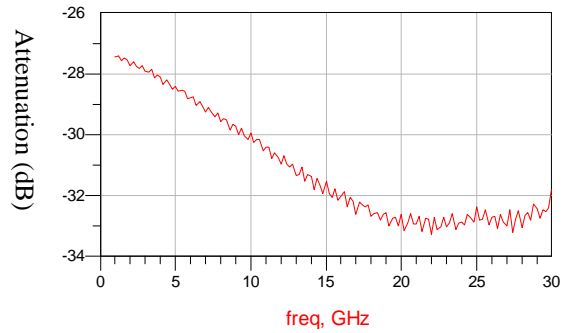
EMR101_C

DC – 26GHz VOLTAGE VARIABLE ATTENUATOR MMIC

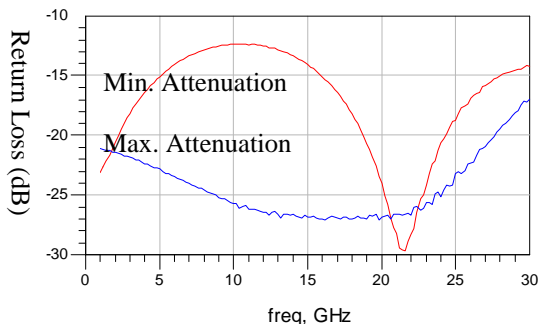
INSERTION LOSS



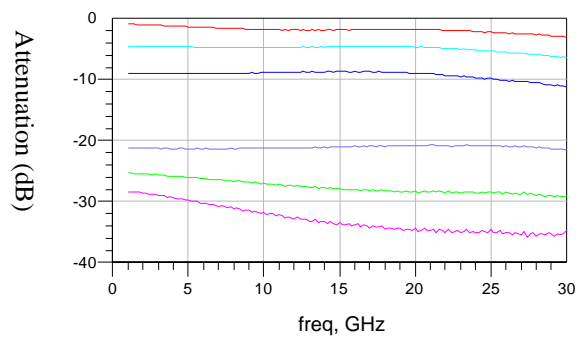
ATTENUATION RANGE



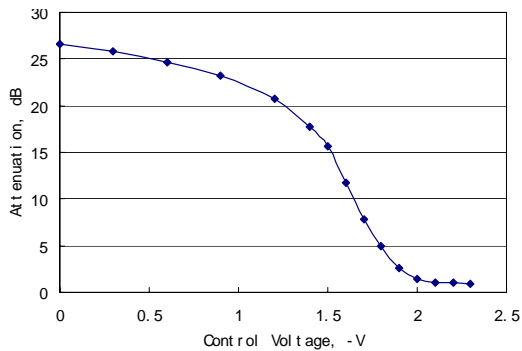
RETURN LOSS



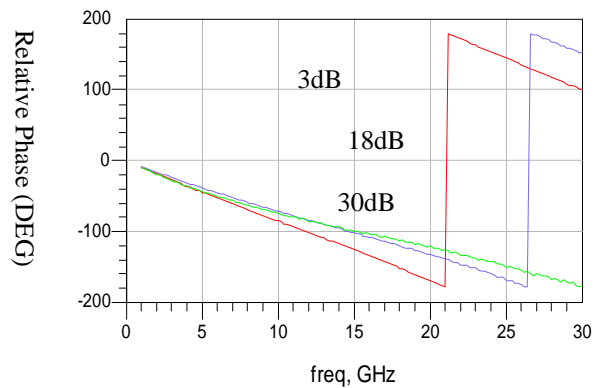
RELATIVE ATTENUATION



RELATIVE ATTENUATION VS. CONTROL VOLTAGE @2GHz



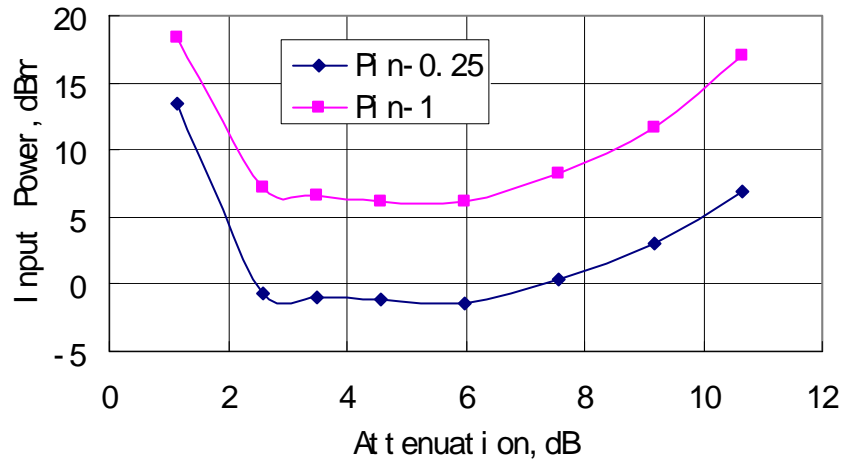
RELATIVE PHASE



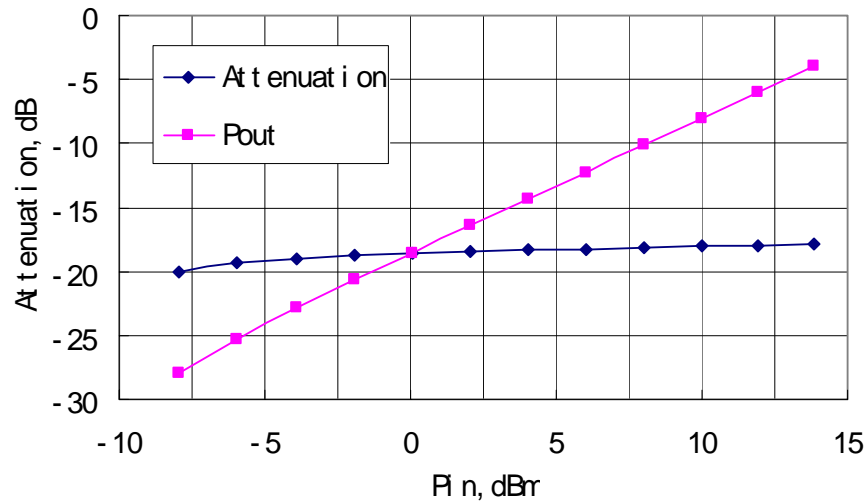


DC – 26GHz VOLTAGE VARIABLE ATTENUATOR MMIC

Input Power at 1dB and 0.25dB Compression VS. Attenuation



Pout and Attenuation VS. Pin at High Attenuation Setting

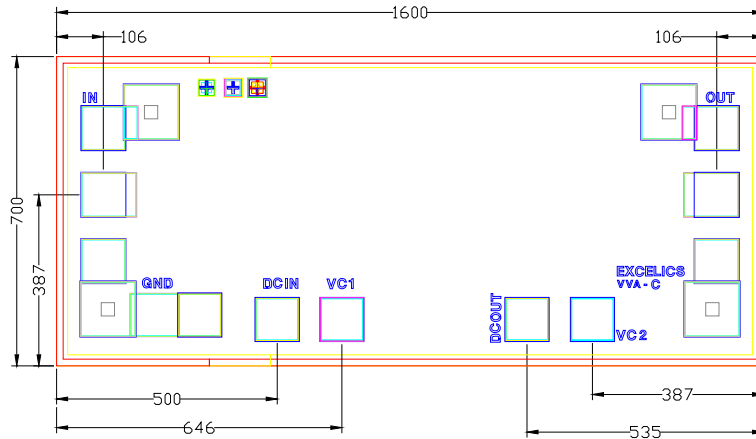




EMR101_C

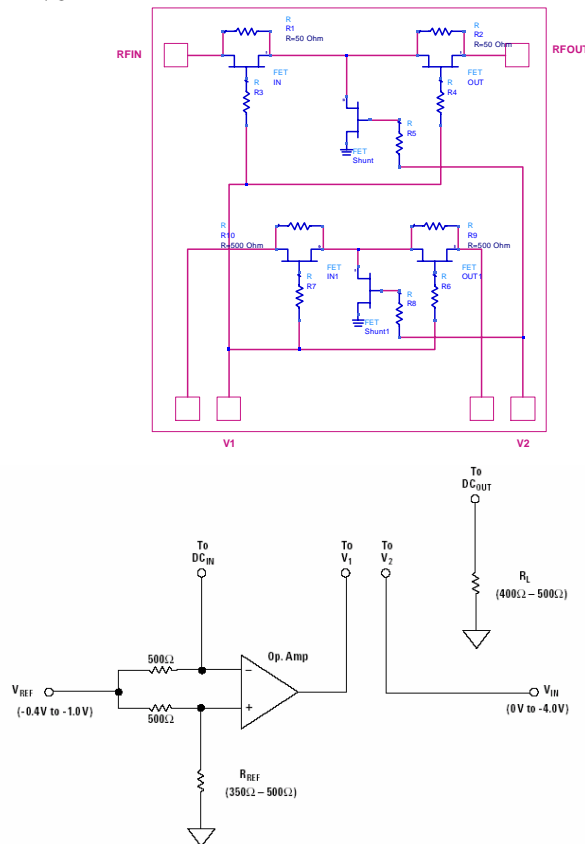
DC – 26GHz VOLTAGE VARIABLE ATTENUATOR MMIC

Outline Drawing



All dimensions in microns
 Bond pads are 100microns by 100microns
 Die thickness is 75 ± 13 microns
 Backside metallization: GOLD
 Bond pads metallization: GOLD

External Op-amp Driver



External op-amp control circuit works with on chip reference circuit to maintain impedance match while attenuation is varied. Input control voltage ranges from 0V (max. attenuation) to -4V (min. attenuation).